

Photocouplers Photorelay

TLP3106A

1. Applications

- · Mechanical relay replacements
- · Factory Automation (FA)
- · Measuring Instruments
- · Security Systems
- I/O Interface Boards

General

The TOSHIBA TLP3106A photorelay consists of a photo MOSFET optically coupled to an infrared LED. It is housed in a 2.54SOP6 package. The low ON-state resistance and the high permissible ON-state current of the TLP3106A make it suitable for power line control applications.

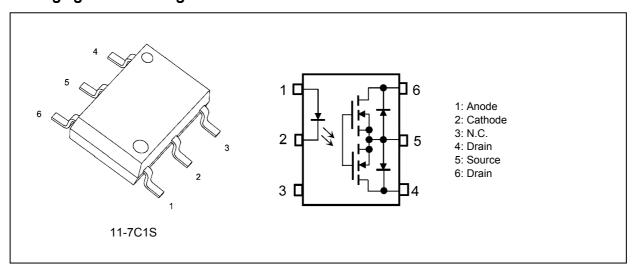
3. Features

- (1) Normally opened (1-Form-A)
- (2) OFF-state output terminal voltage: 30 V (min)
- (3) Trigger LED current: 3 mA (max)
- (4) ON-state current: 4.5 A (max) (A connection)
- (5) ON-state resistance: $30 \text{ m}\Omega$ (max) (A connection)
- (6) Isolation voltage: 1500 Vrms (min)
- (7) Safety standards

UL-recognized: UL 1577, File No.E67349 VDE-approved: EN 60747-5-5 (Note 1)

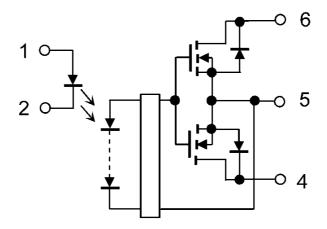
Note 1: When a VDE approved type is needed, please designate the Option (V4).

4. Packaging and Pin Assignment





5. Internal Circuit



6. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

	Characteristics	Symbol	Note	Rating	Unit	
LED	Input forward current		I _F		30	mA
	Input forward current derating	(T _a ≥ 25 °C)	$\Delta I_F/\Delta T_a$		-0.3	mA/°C
	Input forward current (pulsed)	(100 μs pulse, 100 pps)	I _{FP}		1	Α
	Input reverse voltage		V _R		6	V
	Input power dissipation		P _D		50	mW
	Input power dissipation derating	$(T_a \ge 25 ^{\circ}C)$	$\Delta P_D/\Delta T_a$		-0.5	mW/°C
	Junction temperature		Tj		125	°C
Detector	OFF-state output terminal voltage		V _{OFF}		30	V
	ON-state current(A connection)		I _{ON}	(Note 1)	4.5	А
	ON-state current(B connection)		I _{ON}		4.5	
	ON-state current(C connection)		I _{ON}		9	
	ON-state current derating(A connection)	(T _a ≥ 25 °C)	$\Delta I_{ON}/\Delta T_a$	(Note 1)	-45	mA/°C
	ON-state current derating(B connection)	$(T_a \ge 25 ^{\circ}C)$	Δl _{ON} /ΔT _a		-45	
	ON-state current derating(C connection)	(T _a ≥ 25 °C)	Δl _{ON} /ΔT _a		-90	
	ON-state current (pulsed)	(t = 100 ms, Duty = 1/10)	I _{ONP}		13.5	Α
	Output power dissipation		Po		400	mW
	Output power dissipation derating	$(T_a \ge 25 ^{\circ}C)$	$\Delta P_O/\Delta T_a$		-4.0	mW/°C
	Junction temperature		Tj		125	°C
Common	Storage temperature		T _{stg}		-55 to 125	℃
	Operating temperature		T _{opr}		-40 to 110	
	Lead soldering temperature	(10 s)	T _{sol}		260	
	Isolation voltage	(AC, 60 s, R.H. ≤ 60%)	BV _S	(Note 2)	1500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: For an application circuit example, see Chapter 12.2.

Note 2: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.



7. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Supply voltage	V_{DD}		_	_	24	V
Input forward current	I _F		5	10	25	mA
ON-state current(A connection)	I _{ON}			_	4.5	Α
Operating temperature	T _{opr}		-20		85	°C

Note: The recommended operating conditions are given as a design guide necessary to obtain the intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.

8. Electrical Characteristics (Unless otherwise specified, T_a = 25 °C)

	Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
LED	Input forward voltage	V _F		I _F = 10 mA	1.50	1.65	1.80	V
	Input reverse current	I _R		V _R = 5 V			10	μΑ
	Input capacitance	Ct		V = 0 V, f = 1 MHz	_	70		pF
Detector	OFF-state current	I _{OFF}		V _{OFF} = 30 V	_	_	1	μА
Detector	Output capacitance	C _{OFF}		V = 0 V, f = 1 MHz		1200		pF

9. Coupled Electrical Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}		I _{ON} = 1 A	_	0.3	3	mA
Return LED current	I _{FC}		$I_{OFF} = 10\mu A$	0.1	0.3		
ON-state resistance(A connection)	R _{ON}	(Note 1)	$I_F = 5 \text{ mA}, I_{ON} = 4.5 \text{ A}, t < 1 \text{ s}$	_	22	30	mΩ
ON-state resistance(B connection)				_	11	15	
ON-state resistance(C connection)			I _F = 5 mA, I _{ON} = 9 A, t < 1 s		6	8	

Note 1: For an application circuit example, see Chapter 12.2.

10. Isolation Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	(Note 1)	V_S = 500 V, R.H. \leq 60%	5 × 10 ¹⁰	1014	_	Ω
Isolation voltage	BVS	(Note 1)	AC, 60 s	1500			Vrms

Note 1: This device is considered as a two-terminal device: Pins 1, 2 and 3 are shorted together, and pins 4, 5 and 6 are shorted together.



11. Switching Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t _{ON}		See Fig. 11.1. $I_F = 5 \text{ mA}, V_{DD} = 20 \text{ V}, R_L = 200 \Omega$	_	0.6	2	ms
Turn-off time	t _{OFF}		See Fig. 11.1. $I_F = 5 \text{ mA}, V_{DD} = 20 \text{ V}, R_L = 200 \Omega$	_	0.15	0.5	

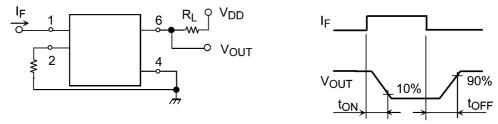


Fig. 11.1 Switching Time Test Circuit and Waveform



12. Characteristics Curves and Circuit Connections

12.1. Characteristics Curves (Note)

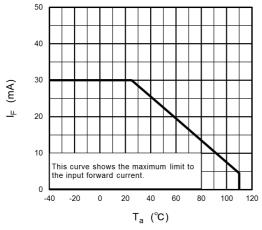


Fig. 12.1.1 I_F - T_a

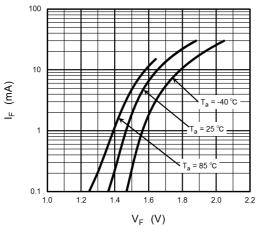


Fig. 12.1.3 I_F - V_F

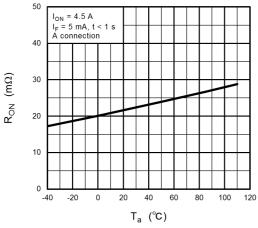


Fig. 12.1.5 R_{ON} - T_a

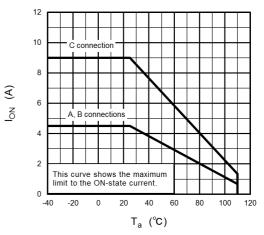


Fig. 12.1.2 I_{ON} - T_a

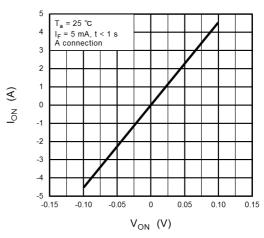


Fig. 12.1.4 I_{ON} - V_{ON}

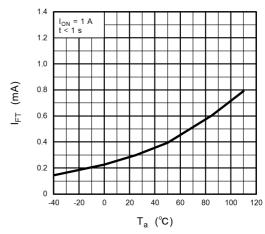


Fig. 12.1.6 I_{FT} - T_a



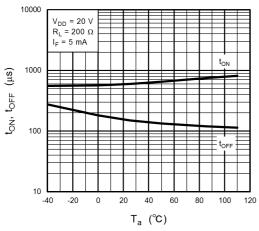
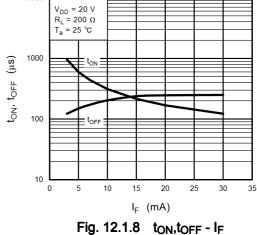


Fig. 12.1.7 t_{ON},t_{OFF} - T_a



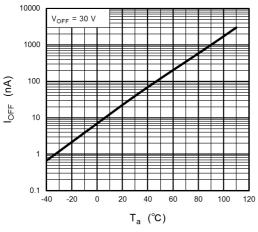


Fig. 12.1.9 I_{OFF} - T_a

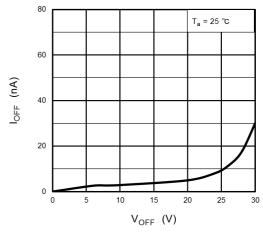


Fig. 12.1.10 | IOFF - VOFF

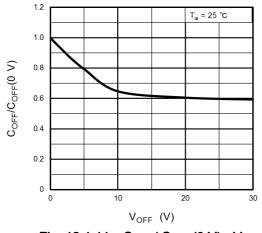


Fig. 12.1.11 C_{OFF}/ C_{OFF}(0 V) - V_{OFF}

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



12.2. Circuit Connections

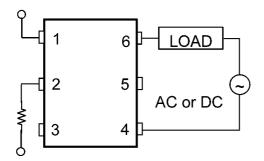


Fig. 12.2.1 A Connection

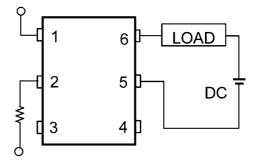


Fig. 12.2.2 B Connection

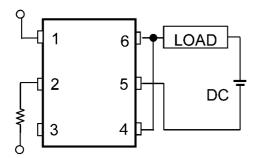


Fig. 12.2.3 C Connection

Rev.2.0



13. Soldering and Storage

13.1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

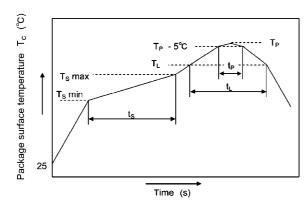
· When using soldering reflow.

The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.



Symbol	Min	Max	Unit
Ts	150	200	°C
t _S	60	120	s
		3	°C/s
T _L	2	17	°C
t _L	60	150	S
T _P		260	°C
t _P		30	s
		6	°C/s
	T _S t _S T _L t _L T _P	T _S 150 t _S 60 T _L 2 t _L 60 T _P	$\begin{array}{c cccc} T_S & 150 & 200 \\ t_S & 60 & 120 \\ & & 3 \\ \hline T_L & 217 \\ t_L & 60 & 150 \\ \hline T_P & 260 \\ \hline t_P & 30 \\ \end{array}$

Fig. 13.1.1 An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

· When using soldering flow

Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds. Mounting condition of 260 °C within 10 seconds is recommended.

Flow soldering must be performed once.

· When using soldering Iron

Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C

Heating by soldering iron must be done only once per lead.

13.2. Precautions for General Storage

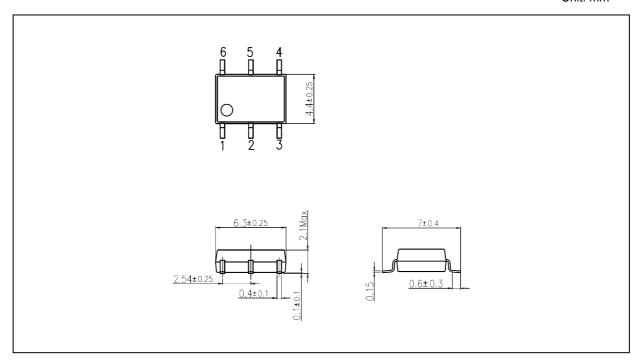
- · Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- Follow the precautions printed on the packing label of the device for transportation and storage.
- Keep the storage location temperature and humidity within a range of 5 °C to 35 °C and 45 % to 75 %, respectively.
- Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- · When restoring devices after removal from their packing, use anti-static containers.
- · Do not allow loads to be applied directly to devices while they are in storage.
- If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

2019-12-26



Package Dimensions

Unit: mm



Weight: 0.13 g (typ.)

	Package Name(s)
TOSHIBA: 11-7C1S	



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